## NSN 5961-01-033-5581

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View Online at https://aerobasegroup.com/nsn/5961-01-033-5581 **Inclosure Material:** Metal **Overall Length:** 0.450 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 0.667 inches and 0.687 inches **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 140.0 reverse voltage, total rms and 250.0 nonrepetitive peak reverse voltage and 200.0 working peak reverse voltage **Current Rating Per Characteristic:** 350.00 amperes forward current, average preset and 40.00 amperes forward current, average absolute **Power Rating Per Characteristic:** 60.0 watts small-signal input power, common-collector preset **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 threaded stud and 1 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No